Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	31306	gate\$4 NEAR20 di\$1electric\$4	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:24
L3	2402	L1 AND (nitrogen\$4 NEAR20 oxide\$4)	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:24
L4	673	L3 AND ((nitrogen\$4 OR nitrous\$4) NEAR20 plasma\$4)	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:25
Ľ5	601	L4 AND transistor\$4	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:23
L6	207	L5 AND (thickness\$4 NEAR20 increas\$4 NEAR20 (oxide\$4 OR di\$1electric\$4))	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:23
L7	2781	(438/761,762,769,770,775,776, 787,791,792).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:24
L9	48	L6 AND L7	US-PGPUB; USPAT	OR	OFF	2005/11/08 14:24
L10	11812	gate\$4 NEAR20 di\$1electric\$4	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/08 14:24
L11	207	L10 AND (nitrogen\$4 NEAR20 oxide\$4)	EPO; JPO; DERWENT; IBM TDB	OR	OFF	2005/11/08 14:25
L12	0	L1 AND ((nitrogen\$4 OR nitrous\$4) NEAR20 plasma\$4)	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/08 14:25